

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L3	233	(257/407).CCLS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/16 13:58
L4	208	(257/388).CCLS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/16 13:59
L5	1159	(257/412).CCLS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/16 13:59
L6	777	gate adj electrode same (Re rhenium) and oxide and (silicon Si)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/16 14:00
L7	338	gate adj electrode with (Re rhenium) and oxide and (silicon Si)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/16 14:01
L8	165	17 and @ad<"20011018"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/16 14:01
L9	77	17 and @riad<"20011018"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/16 14:01
L10	204	18 19	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/08/16 14:01